NSN 5962-01-160-7744

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| View Online at https://aerobasegroup.com/nsn/5962-01-160-7744 |
|---|
| Body Length: |
| 0.840 inches |
| Body Width: |
| Between 0.220 inches and 0.310 inches |
| Body Height: |
| 0.185 inches |
| Maximum Power Dissipation Rating: |
| 739.0 milliwatts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| Radar system an/fps-117 |
| Features Provided: |
| Monolithic and bipolar and programmable and schottky and hermetically sealed |
| Inclosure Material: |
| Ceramic and glass |
| Inclosure Configuration: |
| Dual-in-line |
| Output Logic Form: |
| Transistor-transistor logic |
| Input Circuit Pattern: |
| 10 input |
| Case Outline Source And Designator: |
| D-2 mil-m-38510 |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| 5.5 volts power source |
| Time Rating Per Chacteristic: |
| 75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level |
| output |
| Memory Device Type: |
| Rom |
| Test Data Document: |
| 03538-77a100387 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing |
| etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) |
| Terminal Type And Quantity: |
| 16 printed circuit |
| Shelf Life: |
| N/a |

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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